

MSD42T1G

NPN Silicon General Purpose High Voltage Transistors

This NPN Silicon Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-59 package which is designed for low power surface mount applications.

Features

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{(BR)CBO}$	300	Vdc
Collector-Emitter Voltage	$V_{(BR)CEO}$	300	Vdc
Emitter-Base Voltage	$V_{(BR)EBO}$	6.0	Vdc
Collector Current – Continuous	I_C	150	mAdc

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation (Note 1)	P_D	450	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	274	$^\circ\text{C/W}$
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS

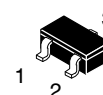
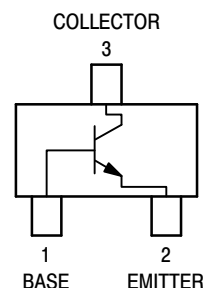
Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage ($I_C = 1.0 \text{ mAdc}$, $I_B = 0$)	$V_{(BR)CEO}$	300	–	Vdc
Collector-Base Breakdown Voltage ($I_C = 100 \mu\text{Adc}$, $I_E = 0$)	$V_{(BR)CBO}$	300	–	Vdc
Emitter-Base Breakdown Voltage ($I_E = 100 \mu\text{Adc}$, $I_C = 0$)	$V_{(BR)EBO}$	6.0	–	Vdc
Collector-Base Cutoff Current ($V_{CB} = 200 \text{ Vdc}$, $I_E = 0$)	I_{CBO}	–	0.1	μA
Emitter-Base Cutoff Current ($V_{EB} = 6.0 \text{ Vdc}$, $I_B = 0$)	I_{EBO}	–	0.1	μA
DC Current Gain (Note 2) ($V_{CE} = 10 \text{ Vdc}$, $I_C = 1.0 \text{ mAdc}$) ($V_{CE} = 10 \text{ Vdc}$, $I_C = 30 \text{ mAdc}$)	h_{FE1} h_{FE2}	25 40	– –	–
Collector-Emitter Saturation Voltage (Note 2) ($I_C = 20 \text{ mAdc}$, $I_B = 2.0 \text{ mAdc}$)	$V_{CE(sat)}$	–	0.5	Vdc

- FR-4 @ 10 mm², 1 oz. Copper traces.
- Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, D.C. $\leq 2\%$.



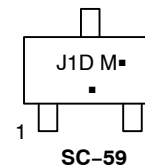
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SC-59
CASE 318D
STYLE 1

MARKING DIAGRAM



J1D = Specific Device Code
M = Date Code
▪ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
MSD42T1G	SC-59 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL CHARACTERISTICS

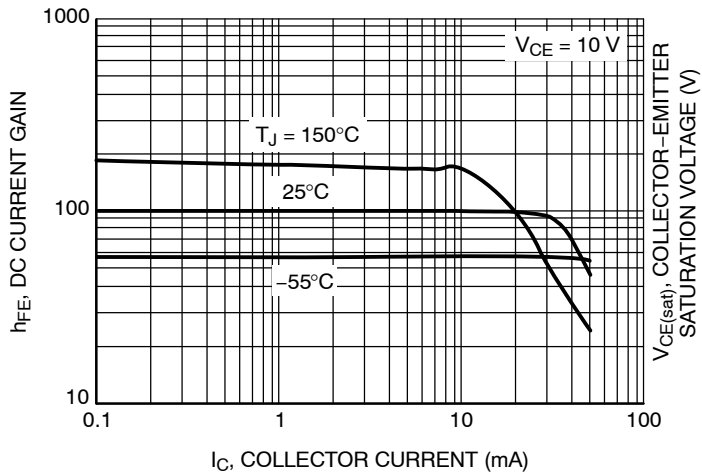


Figure 1. DC Current Gain

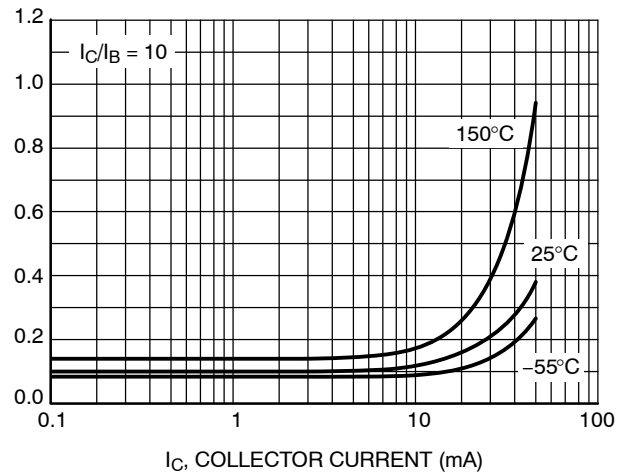


Figure 2. Collector-Emitter Saturation Voltage vs. Collector Current

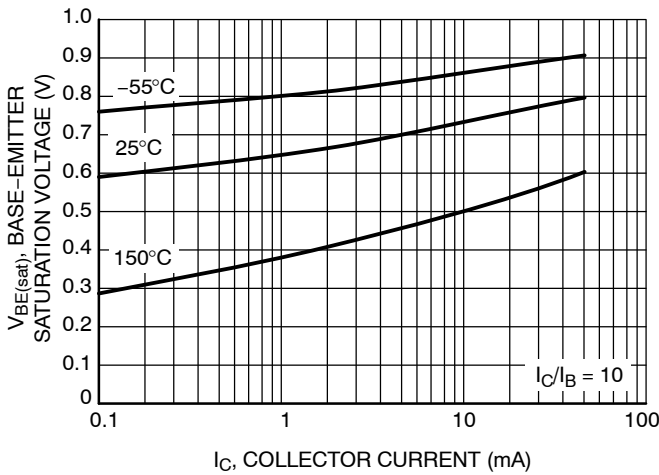


Figure 3. Base-Emitter Saturation Voltage vs. Collector Current

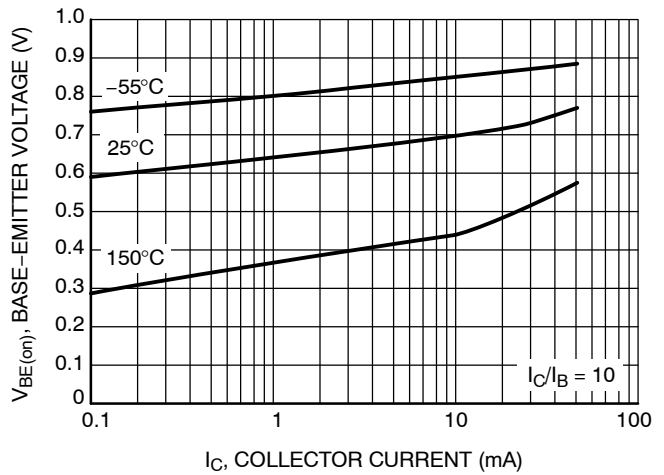


Figure 4. Base-Emitter On Voltage vs. Collector Current

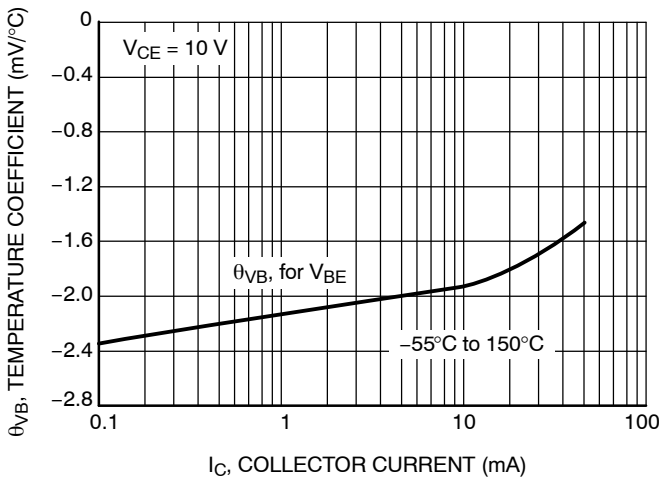


Figure 5. Base-Emitter Temperature Coefficient

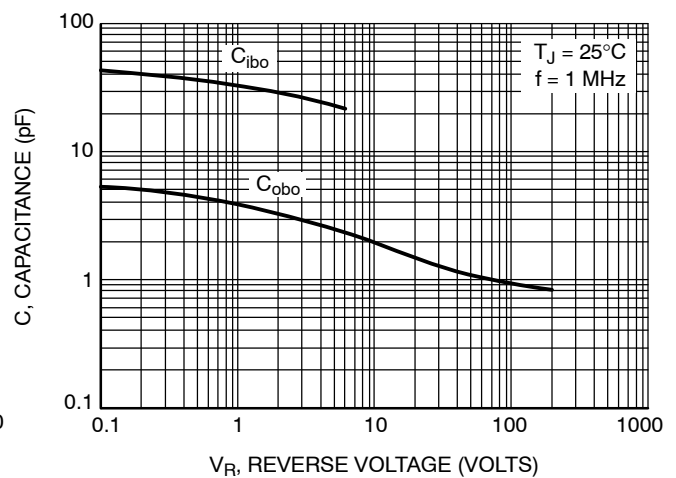


Figure 6. Capacitance

MSD42T1G

TYPICAL CHARACTERISTICS

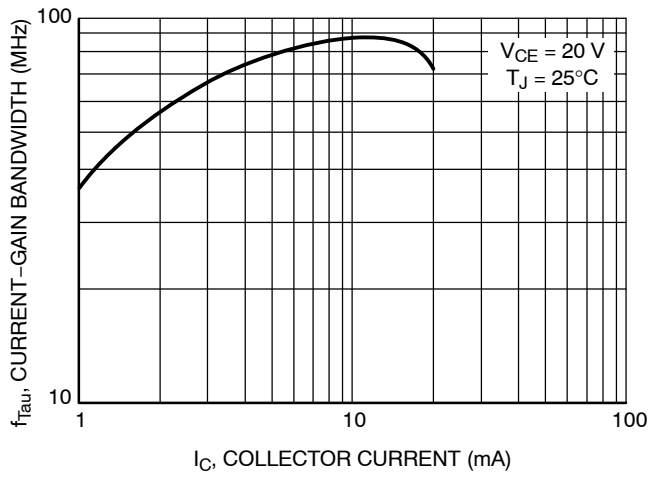


Figure 7. Current-Gain — Bandwidth Product

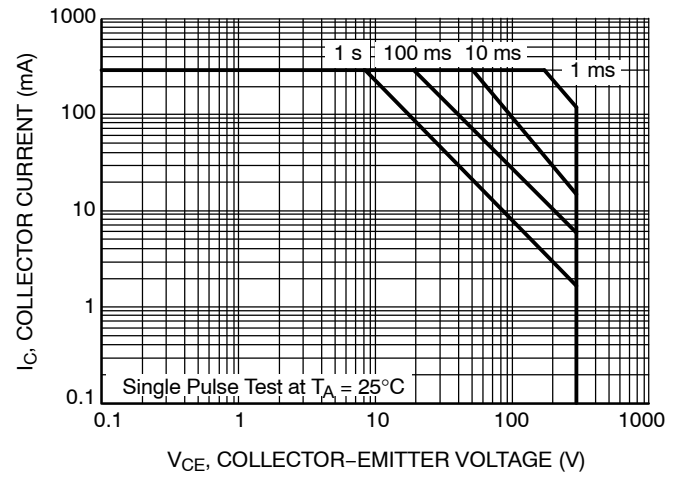


Figure 8. Safe Operating Area

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

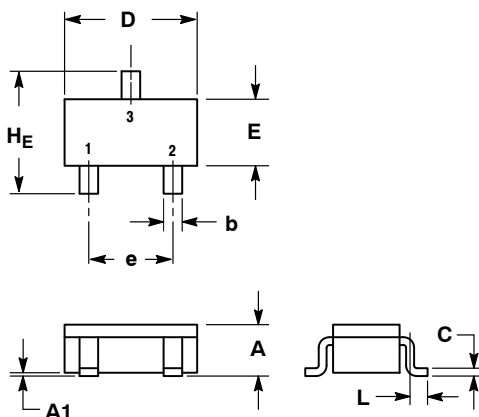
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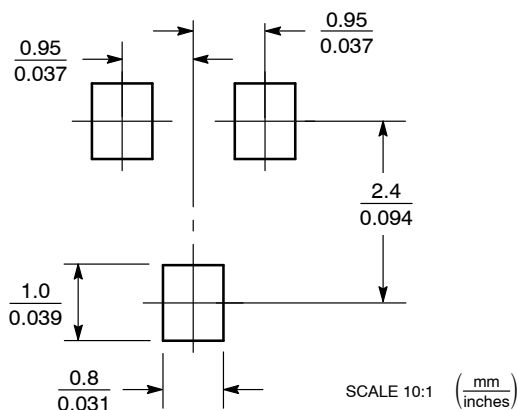
SCALE 2:1

SC-59
CASE 318D-04
ISSUE H

DATE 28 JUN 2012



SOLDERING FOOTPRINT*

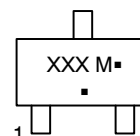


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.00	1.15	1.30	0.039	0.045	0.051
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.35	0.43	0.50	0.014	0.017	0.020
c	0.09	0.14	0.18	0.003	0.005	0.007
D	2.70	2.90	3.10	0.106	0.114	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	1.70	1.90	2.10	0.067	0.075	0.083
L	0.20	0.40	0.60	0.008	0.016	0.024
H_E	2.50	2.80	3.00	0.099	0.110	0.118

GENERIC MARKING DIAGRAM



XXX = Specific Device Code
M = Date Code
▪ = Pb-Free Package*

(*Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

STYLE 1: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 2: PIN 1. ANODE 2. N.C. 3. CATHODE	STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE
STYLE 4: PIN 1. CATHODE 2. N.C. 3. ANODE	STYLE 5: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 6: PIN 1. ANODE 2. CATHODE 3. ANODE/CATHODE

DOCUMENT NUMBER: 98ASB42664B

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DESCRIPTION: SC-59

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